

74VHC245 • 74VHCT245

Octal Bidirectional Transceiver with 3-STATE Outputs

General Description

The VHC/VHCT245 is an advanced high speed CMOS octal bus transceiver fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHC245 is intended for bidirectional asynchronous communication between data busses. The direction of data transmission is determined by the level of the T/R input. The enable input can be used to disable the device so that the busses are effectively isolated. All inputs are equipped with protection circuits against static discharge.

Features

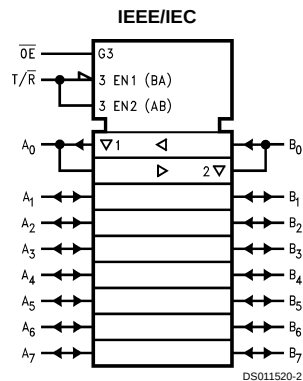
- High Speed:
 - VHC $t_{pd} = 4.0$ ns (typ) at $V_{CC} = 5V$
 - VHCT $t_{pd} = 5.3$ ns (typ) at $V_{CC} = 5V$
- High Noise Immunity:
 - VHC $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min)
 - VHCT $V_{IH} = 2.0V$, $V_{IL} = 0.8V$
- Power Down Protection:
 - VHC Inputs Only
 - VHCT Inputs and Outputs
- Low Noise:
 - VHC $V_{OLP} = 0.9V$ (typ)
 - VHCT $V_{OLP} = 1.1V$ (typ)
- Low Power Dissipation:
 - $I_{CC} = 4 \mu A$ (Max) @ $T_A = 25^\circ C$
- Pin and Function Compatible with 74HC/HCT245

Ordering Code:

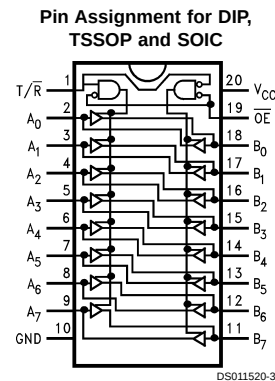
Commercial	Package Number	Package Description
74VHC245M	M20B	20 Lead Molded JEDEC SOIC
74VHC245SJ	M20D	20 Lead Molded EIAJ SOIC
74VHC245MTC	MTC20	20 Lead Molded JEDEC Type 1 TSSOP
74VHC245N	N20A	20 Lead Molded DIP
74VHCT245M	M20B	20 Lead Molded JEDEC SOIC
74VHCT245SJ	M20D	20 Lead Molded EIAJ SOIC
74VHCT245MTC	MTC20	20 Lead Molded JEDEC Type 1 TSSOP
74VHCT245N	N20A	20 Lead Molded DIP

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Description

Pin Names	Description
$\overline{OE}$	Output Enable Input
$T/\overline{R}$	Transmit/Receive Input
A_0-A_7	Side A Inputs or 3-STATE Outputs
B_0-B_7	Side B Inputs or 3-STATE Outputs

Truth Tables

Inputs		Outputs
$\overline{OE}$	$T/\overline{R}$	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	HIGH-Z State

H = HIGH Voltage Level X = Immaterial

L = LOW Voltage Level

Any unused bus terminals during HIGH-Z State must be held HIGH or LOW.

Absolute Maximum Ratings (Note 2)

Supply Voltage (V_{CC})	-0.5V to +7.0V
DC Input Voltage (V_{IN}) ($\overline{T/R}$, $\overline{OE}$)	-0.5V to 7.0V
DC Output Voltage (V_{OUT})	
VHC	-0.5V to $V_{CC} + 0.5V$
VHCT (Note 1)	-0.5V to 7.0V
Input Diode Current (I_{IK}) ($\overline{T/R}$, $\overline{OE}$)	-20 mA
Output Diode Current (I_{OK})	
VHC	±20 mA
VHCT	-20 mA
DC Output Current (I_{OUT})	±25 mA
DC V_{CC}/GND Current (I_{CC})	±75 mA
Storage Temperature (T_{STG})	-65°C to +150°C
Lead Temperature (T_L)	
(Soldering, 10 seconds)	260°C

Recommended Operating Conditions (Note 3)

Supply Voltage (V_{CC})	
VHC	2.0V to 5.5V
VHCT (Note 1)	4.5V to 5.5V
Input Voltage (V_{IN}) ($\overline{T/R}$, $\overline{OE}$)	0V to 5.5V
Output Voltage (V_{OUT})	0V to V_{CC}
Operating Temperature (T_{OPR})	-40°C to +85°C
Input Rise and Fall Time (t_r , t_f)	
$V_{CC} = 3.3V \pm 0.3V$ (VHC only)	0 ~ 100 ns/V
$V_{CC} = 5.0V \pm 0.5V$	0 ~ 20 ns/V

Note 1: $V_{OUT} > V_{CC}$ only if output is in H or Z state.

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 3: Unused inputs or I/O pins must be held HIGH or LOW. They may not float.

DC Characteristics for VHC Family Devices

Symbol	Parameter	V _{CC} (V)	T _A = 25°C			T _A = -40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
V _{IH}	High Level Input Voltage	2.0 3.0–5.5	1.50 0.7 V _{CC}			1.50 0.7 V _{CC}		V		
V _{IL}	Low Level Input Voltage	2.0 3.0–5.5	0.50 0.3 V _{CC}			0.50 0.3 V _{CC}		V		
V _{OH}	High Level Output Voltage	2.0	1.9	2.0		1.9		V	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA
		3.0	2.9	3.0		2.9				
		4.5	4.4	4.5		4.4		V		I _{OH} = -4 mA I _{OH} = -8 mA
		3.0 4.5	2.58 3.94			2.48 3.80				
V _{OL}	Low Level Output Voltage	2.0		0.0	0.1		0.1	V	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA
		3.0		0.0	0.1		0.1			
		4.5		0.0	0.1		0.1	V		I _{OL} = 4 mA I _{OL} = 8 mA
		3.0 4.5			0.36 0.36		0.44 0.44			
I _{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V _{IN} = V _{CC} or GND V _{OUT} = V _{CC} or GND V _{IN} $\overline{OE}$ = V _{IH} or V _{IL}	
I _{IN} (T/R, $\overline{OE}$)	Input Leakage Current	0–5.5			±0.1		±1.0	μA	V _{IN} = 5.5V or GND	
I _{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V _{IN} = V _{CC} or GND	

DC Characteristics for VHC Family Devices

Symbol	Parameter	V _{CC} (V)	T _A = 25°C		Units	Conditions
			Typ	Limits		
V _{OLP} (Note 4)	Quiet Output Maximum Dynamic V _{OL}	5.0	0.9	1.2	V	C _L = 50 pF
V _{OLV} (Note 4)	Quiet Output Minimum Dynamic V _{OL}	5.0	-0.9	-1.2	V	C _L = 50 pF
V _{IHD} (Note 4)	Minimum High Level Dynamic Input Voltage	5.0		3.5	V	C _L = 50 pF
V _{ILD} (Note 4)	Maximum Low Level Dynamic Input Voltage	5.0		1.5	V	C _L = 50 pF

Note 4: Parameter guaranteed by design.

DC Characteristics for VHCT Family Devices

Symbol	Parameter	V _{CC} (V)	T _A = 25°C			T _A = -40°C to +85°C		Units	Conditions
			Min	Typ	Max	Min	Max		
V _{IH}	High Level Input Voltage	4.5 5.5	2.0 2.0			2.0 2.0		V	
V _{IL}	Low Level Input Voltage	4.5 5.5			0.8 0.8		0.8 0.8	V	
V _{OH}	High Level Output Voltage	4.5	3.15	3.65		3.15		V	V _{IN} = V _{IH} I _{OH} = -50 μA
		4.5	2.5			2.4		V	or V _{IL} I _{OH} = -8 mA
V _{OL}	Low Level Output Voltage	4.5		0.0	0.1		0.1	V	V _{IN} = V _{IH} I _{OL} = 50 μA
		4.5			0.36		0.44	V	or V _{IL} I _{OL} = 8 mA
I _{OZ}	3-STATE Output Off-State Current	5.5			±0.25		±2.5	μA	V _{IN} = V _{CC} or GND V _{OUT} = V _{CC} or GND V _{IN} OE = V _{IH} or V _{IL}
I _{IN} (T/R, OE)	Input Leakage Current	0-5.5			±0.1		±1.0	μA	V _{IN} = 5.5V or GND
I _{CC}	Quiescent Supply Current	5.5			4.0		40.0	μA	V _{IN} = V _{CC} or GND
I _{CCT}	Maximum I _{CC} /Input	5.5			1.35		1.50	mA	V _{IN} = 3.4V Other Inputs = V _{CC} or GND
I _{OFF}	Output Leakage Current (Power Down State)	0.0			+0.5		+5.0	μA	V _{OUT} = 5.5V

DC Characteristics for VHCT Family Devices

Symbol	Parameter	V _{CC} (V)	T _A = 25°C		Units	Conditions
			Typ	Limits		
V _{OLP} (Note 5)	Quiet Output Maximum Dynamic V _{OL}		1.1	1.6	V	C _L = 50 pF
V _{OLV} (Note 5)	Quiet Output Minimum Dynamic V _{OL}		-1.1	-1.6	V	C _L = 50 pF
V _{IHD} (Note 5)	Minimum High Level Dynamic Input Voltage			2.0	V	C _L = 50 pF
V _{ILD} (Note 5)	Maximum Low Level Dynamic Input Voltage			0.8	V	C _L = 50 pF

Note 5: Parameter guaranteed by design.

AC Electrical Characteristics for VHC Family Devices

Symbol	Parameter	V _{CC} (V)	T _A = 25°C			T _A = -40°C to +85°C		Units	Conditions	
			Min	Typ	Max	Min	Max			
t _{PLH} t _{PHL}	Propagation Delay Time	3.3 ± 0.3		5.8	8.4	1.0	10.0	ns		C _L = 15 pF
				8.3	11.9	1.0	13.5			C _L = 50 pF
		5.0 ± 0.5		4.0	5.5	1.0	6.5	ns		C _L = 15 pF
				5.5	7.5	1.0	8.5			C _L = 50 pF
t _{PZL} t _{PZH}	3-STATE Output Enable Time	3.3 ± 0.3		8.5	13.2	1.0	15.5	ns	R _L = 1 kΩ	C _L = 15 pF
				11.0	16.7	1.0	19.0			C _L = 50 pF
		5.0 ± 0.5		5.8	8.5	1.0	10.0	ns		C _L = 15 pF
				7.3	10.6	1.0	12.0			C _L = 50 pF
t _{PLZ} t _{PHZ}	3-STATE Output Disable Time	3.3 ± 0.3		11.5	15.8	1.0	18.0	ns	R _L = 1 kΩ	C _L = 50 pF
		5.0 ± 0.5		7.0	9.7	1.0	11.0			C _L = 50 pF
t _{OSLH}	Output to Output	3.3 ± 0.3			1.5		1.5	ns	(Note 6)	C _L = 50 pF
t _{OSHL}	Skew	5.0 ± 0.5			1.0		1.0			C _L = 50 pF
C _{IN} (T/R, OE)	Input Capacitance			4	10		10	pF	V _{CC} = Open	
C _{IO}	Output Capacitance			8				pF	V _{CC} = 5.0V	
C _{PD}	Power Dissipation Capacitance			21				pF	(Note 7)	

Note 6: Parameter guaranteed by design. t_{OSLH} = |t_{PLH} max - t_{PLH} min|; t_{OSHL} = |t_{PHL} max - t_{PHL} min|

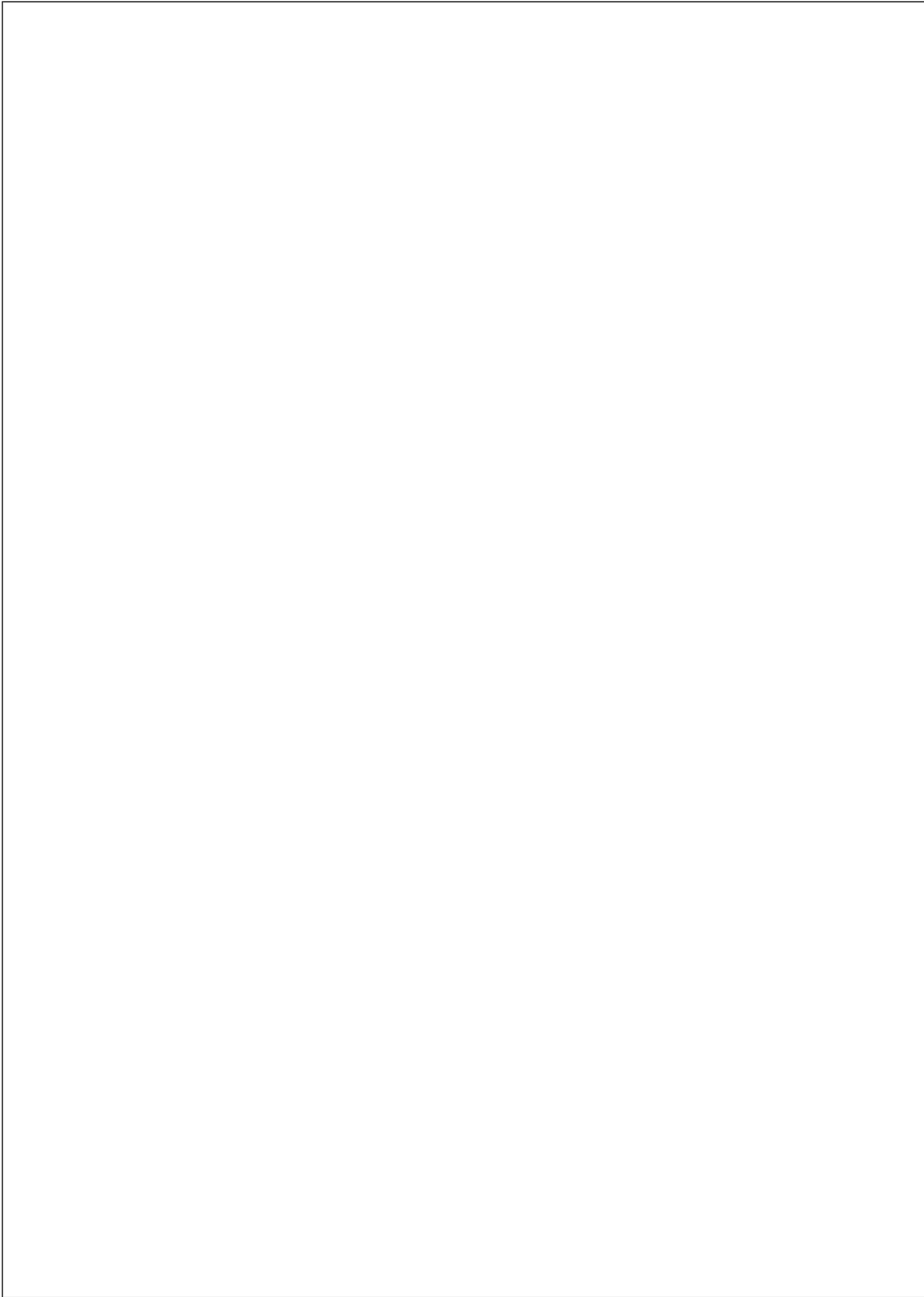
Note 7: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/8 (per Bit).

AC Electrical Characteristics for VHCT Family Devices

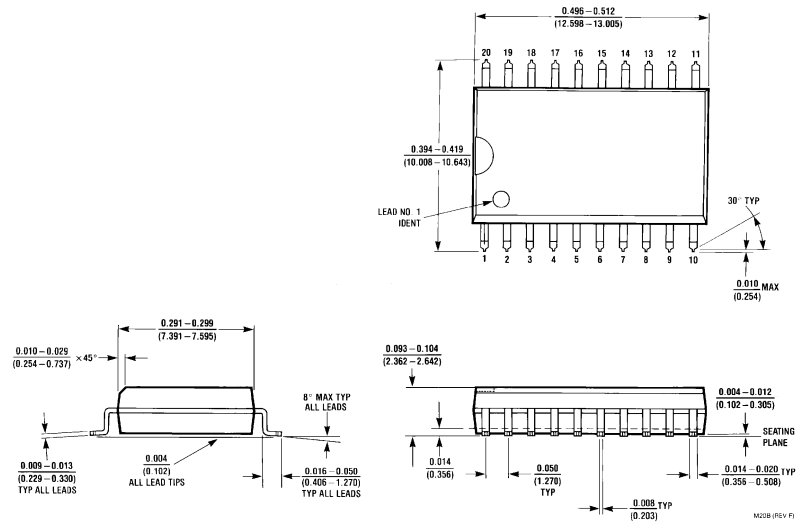
Symbol	Parameter	V _{CC} (V)	T _A = 25°C			T _A = −40°C to +85°C		Units	Conditions		
			Min	Typ	Max	Min	Max				
t _{PLH}	Propagation Delay	5.0 ±0.5	4.5	7.7	1.0	8.5	ns		C _L = 15 pF		
t _{PHL}	Time		5.3	8.7	1.0	9.5			C _L = 50 pF		
t _{PZL}	3-STATE Output	5.0 ±0.5	8.9	13.8	1.0	15.0	ns	R _L = 1 kΩ	C _L = 15 pF		
t _{PZH}	Enable Time		9.7	14.8	1.0	16.0			C _L = 50 pF		
t _{PLZ}	3-STATE Output	5.0 ±0.5	10.0	15.4	1.0	16.5	ns	R _L = 1 kΩ	C _L = 50 pF		
t _{PHZ}	Disable Time										
t _{OSLH}	Output to Output Skew	5.0 ±0.5	1.0			1.0		ns	(Note 8)	C _L = 50 pF	
t _{OSHL}											
C _{IN}	Input Capacitance		4	10	10		pF	V _{CC} = Open			
C _{I/O}	Output Capacitance		9					pF	V _{CC} = 5.0V		
C _{PD}	Power Dissipation Capacitance		23					pF	(Note 9)		

Note 8: Parameter guaranteed by design. t_{OSLH} = |t_{PLH} max - t_{PLH} min|; t_{OSHL} = |t_{PHL} max - t_{PHL} min|

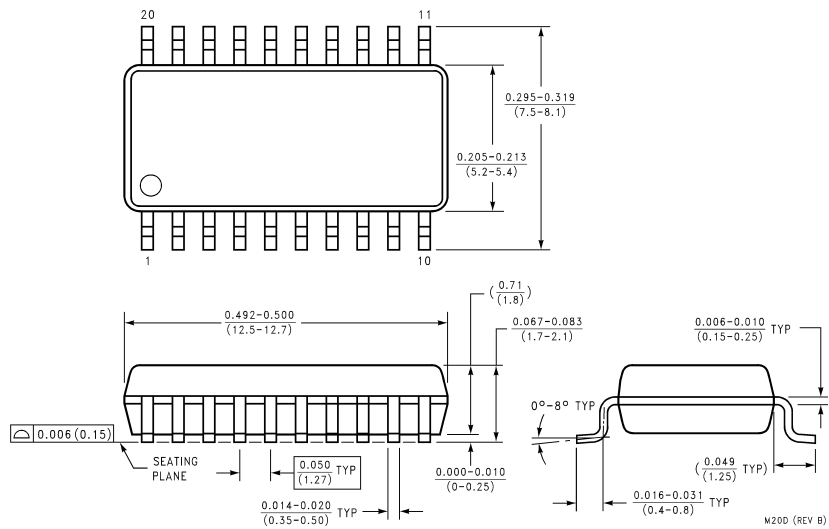
Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/8 (per Bit).



Physical Dimensions inches (millimeters) unless otherwise noted



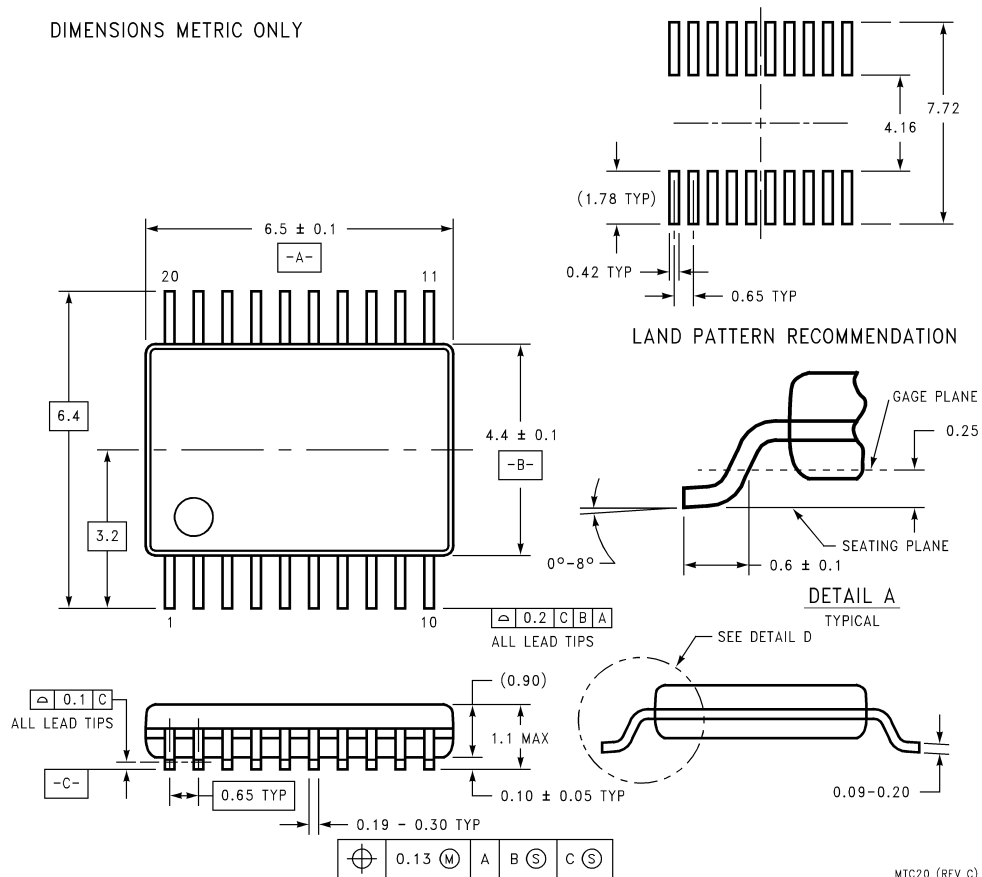
20-Lead Small Outline Package —JEDEC SOIC (M)
Package Number M20B



20-Lead Small Outline Package EIAJ SOIC (SJ)
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)

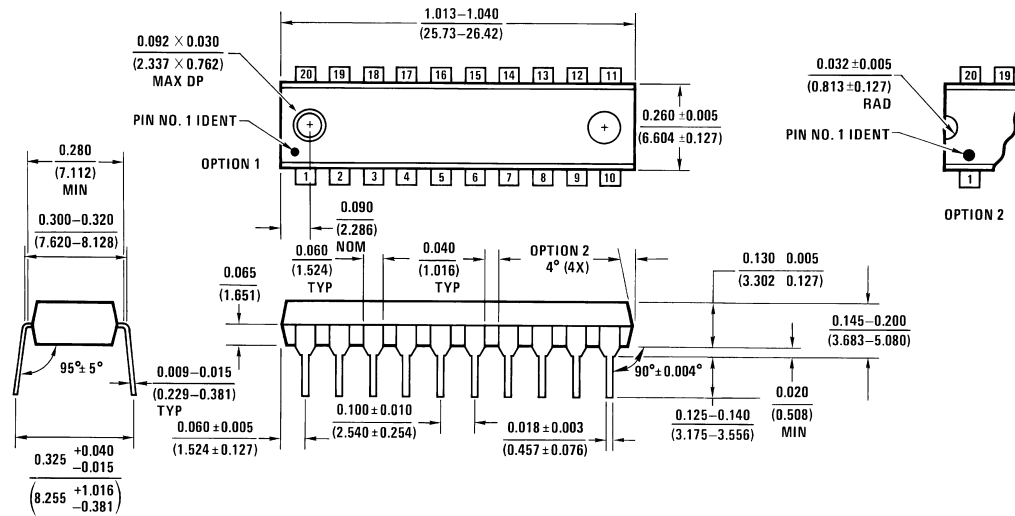
DIMENSIONS METRIC ONLY



**20-Lead Plastic JEDEC TSSOP Type I (MTC)
Package Number MTC20**

MTC20 (REV C)

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead (0.300" Wide) Molded Dual-In-Line Package
Package Number N20A

N20A (REV G)

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